

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

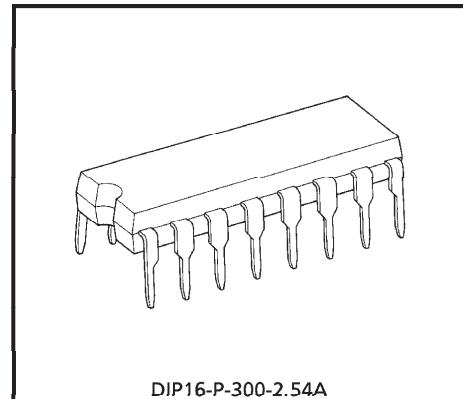
## TA8119P

## STEREO HEADPHONE AMPLIFIER (3V USE)

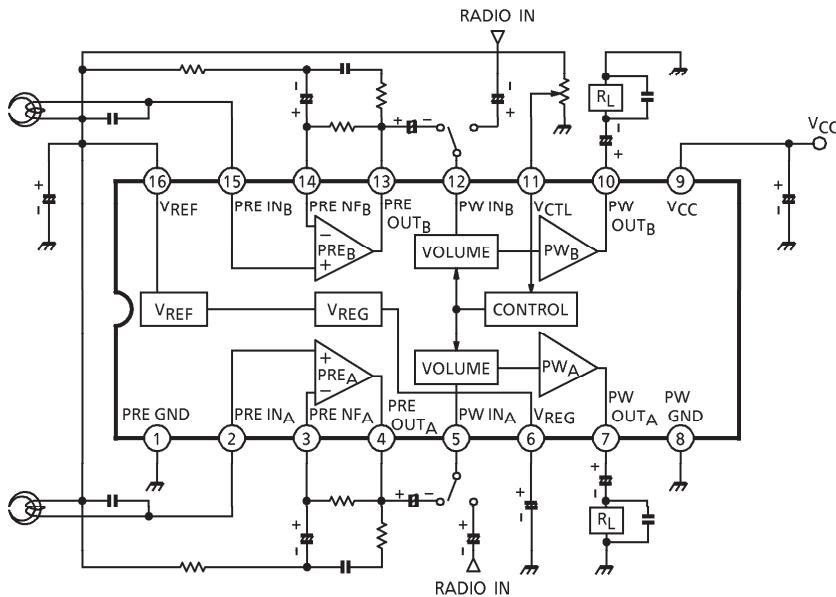
The TA8119P is developed for play-back stereo headphone player (3V use), which is built-in preamplifiers, power amplifiers (for headphone) and DC volume controls.

## FEATURES

- Built-in DC volume controls
- Coupling condenser-less for input of preamplifier
- The loop gain of power amplifier is 30dB (Typ.), in case that DC volume is at maximum
- Available of external input signal from DC volume stage
- Low quiescent current ( $V_{CC} = 3V$ ,  $T_a = 25^\circ C$ )  
 $I_{CCQ} = 9mA$  (Typ.)
- Operating supply voltage range ( $T_a = 25^\circ C$ )  
 $V_{CC} (\text{opr}) = 1.8\sim 6V$



## BLOCK DIAGRAM



961001EBA2

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**PIN FUNCTION**Terminal voltage : Typical terminal voltage at no signal with test circuit ( $V_{CC} = 3V$ ,  $T_a = 25^\circ C$ )

PIN No.	PIN NAME	CONTENTS	EQUIVALENT	TERMINAL VOLTAGE (V)
1	PRE GND	—	—	0
2	PRE IN <sub>A</sub>	Input of preamplifier		1.3
15	PRE IN <sub>B</sub>			
3	PRE NFA	NF of preamplifier		1.3
14	PRE NF <sub>B</sub>			
4	PRE OUT <sub>A</sub>	Output of preamplifier		1.3
13	PRE OUT <sub>B</sub>			
5	PW IN <sub>A</sub>	Input of power amplifier for headphone (through DC volume stage)		1.3
12	PW IN <sub>B</sub>			
6	V <sub>REG</sub>	Ripple filter of power supply		2.6
16	V <sub>REF</sub>	Reference voltage		1.3
7	PW OUT <sub>A</sub>	Output of power amplifier		1.3
10	PW OUT <sub>B</sub>			
8	PW GND	—	—	0
9	V <sub>CC</sub>	—	—	3
11	V <sub>CTL</sub>	Input of control voltage for volume control		—

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**APPLICATION NOTE**

- (1) A volume which has the characteristic "curve A" is available for the DC volume control.
- (2) The capacitor C is used for absorbing volume sliding noise.
- (3) The DC volume control circuit is applicable to "Function of Mute", connecting as Fig.1.  
In case of tuning mute-on, the load of "Reference voltage circuit" is R, at maximum volume.
- (4) Small temperature coefficient and excellent frequency characteristic is needed by capacitors below.
- Oscillation preventing capacitors for power amplifier output.
  - Capacitor between V<sub>REF</sub> and GND.
  - Capacitor between V<sub>CC</sub> and GND.
  - Capacitor between V<sub>REG</sub> and GND.

**MAXIMUM RATINGS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	7	V
Output Current	I <sub>O</sub> (peak)	120	mA
Power Dissipation	P <sub>D</sub> (Note)	750	mW
Operating Temperature	T <sub>opr</sub>	-25~75	°C
Storage Temperature	T <sub>stg</sub>	-55~150	°C

(Note) Derated above Ta = 25°C in the proportion of 6mW / °C.

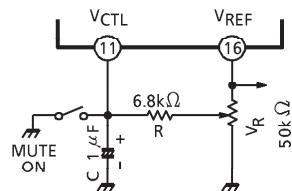


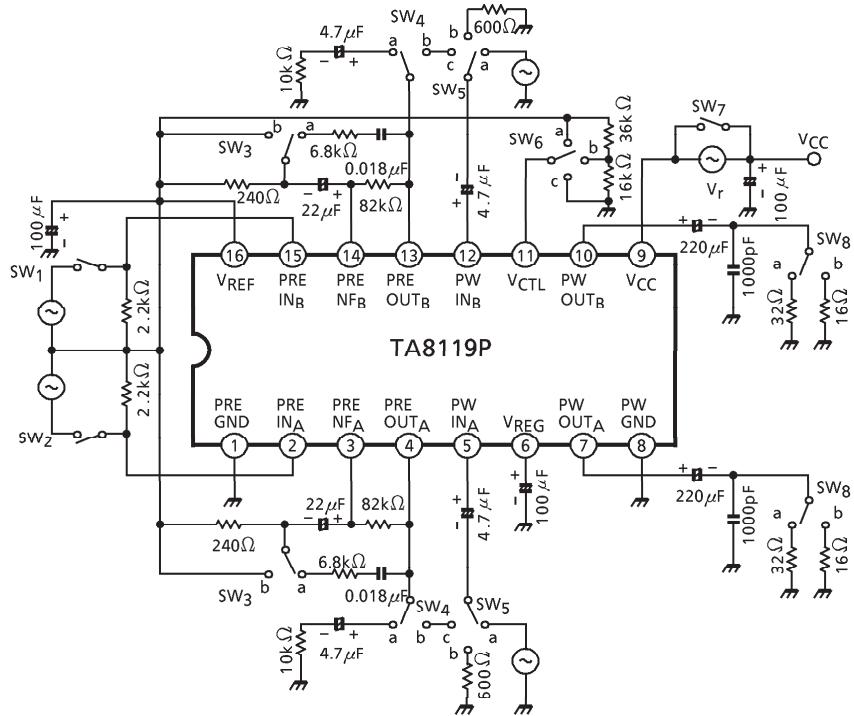
Fig.1 Function of mute

**ELECTRICAL CHARACTERISTICS**

Unless otherwise specified,  $V_{CC} = 3V$ ,  $T_a = 25^\circ C$ ,  $f = 1\text{kHz}$   
 Preamplifier :  $R_L = 10k\Omega$ ,  $\text{Vol} = \text{MIN}$   
 Power amplifier :  $R_L = 32\Omega$ ,  $\text{Vol} = \text{MAX}$

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Quiescent Supply Current	$I_{CCQ1}$	—	—	$V_{in} = 0$ , $\text{Vol} = \text{MIN}$	—	9.0	13.0	mA
	$I_{CCQ2}$	—	—	$V_{in} = 0$ , $\text{Vol} = \text{MAX}$	—	11.0	—	
Preamplifier Section	Open Loop Voltage Gain	$G_{VO}$	—	$V_O = -12\text{dBV}$	55	62	—	dB
	Closed Loop Voltage Gain	$G_{VC}$	—	$NAB = 1\text{kHz}$ , $V_O = -12\text{dBV}$	—	33	—	dB
	Maximum Output Voltage	$V_{om}$	—	$\text{THD} = 1\%$	600	720	—	$\text{mV}_{\text{rms}}$
	Total Harmonic Distortion	$\text{THD1}$	—	$V_O = -12\text{dBV}$	—	0.04	0.1	%
	Equivalent Input Noise Voltage	$V_{ni}$	—	$R_g = 2.2k\Omega$ $\text{BPF} = 30\text{Hz} \sim 20\text{kHz}$ $NAB$ ( $G_V = 33\text{dB}$ , $f = 1\text{kHz}$ )	—	1.2	2.0	$\mu\text{V}_{\text{rms}}$
	Ripple Rejection Ratio	$RR1$	—	$R_g = 2.2k\Omega$ $V_r = -22\text{dBV}$ , $f_r = 100\text{Hz}$	—	46	—	dB
Power Amplifier Section	Output Power (1)	$P_{o1}$	—	$\text{THD} = 10\%$	20	27	—	mW
		$P_{o2}$	—	$R_L = 16\Omega$ , $\text{THD} = 10\%$	—	39	—	
	Voltage Gain (1)		$G_{V1}$	$V_O = -12\text{dBV}$	28	30	32	dB
	Channel Balance		$CB$		—	0	1.5	dB
	Voltage Gain (2)		$G_{V2}$	$V_O = -12\text{dBV}$ , $\text{Vol} = \text{MID}$	—	15	—	dB
	Total Harmonic Distortion		$\text{THD2}$		$P_O = 10\text{mW}$	—	0.5	1.2
			$\text{THD3}$		$P_O = 10\text{mW}$ , $\text{Vol} = \text{MID}$	—	0.3	—
	Output Noise Voltage	$V_{no}$	—	$R_g = 600\Omega$ $\text{BPF} = 30\text{Hz} \sim 20\text{kHz}$	—	250	320	$\mu\text{V}_{\text{rms}}$
	Maximum Attenuation	$ATT$	—	$V_O = -12\text{dBV}$ $\text{Vol} = \text{MAX} \rightarrow \text{MIN}$	66	72	—	dB
	Ripple Rejection Ratio	$RR2$	—	$R_g = 600\Omega$ $V_r = -22\text{dBV}$ , $f_r = 100\text{Hz}$	—	46	—	dB
Total	Cross Talk (CH-A / CH-B)	$CT$	—	$R_g = 2.2k\Omega$ $V_O = -12\text{dBV}$ , $\text{Vol} = \text{MAX}$	34	40	—	dB

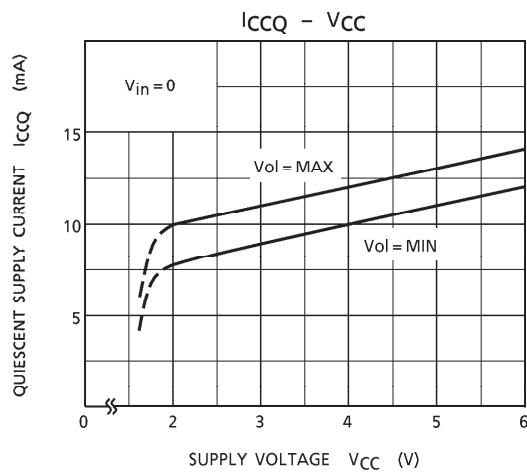
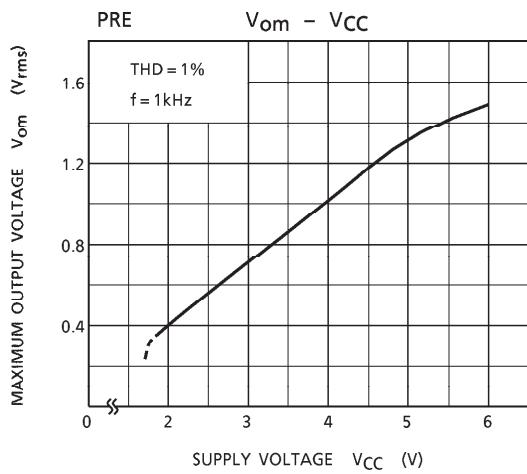
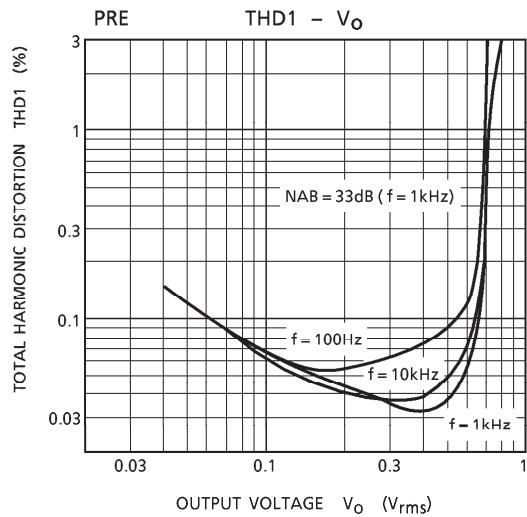
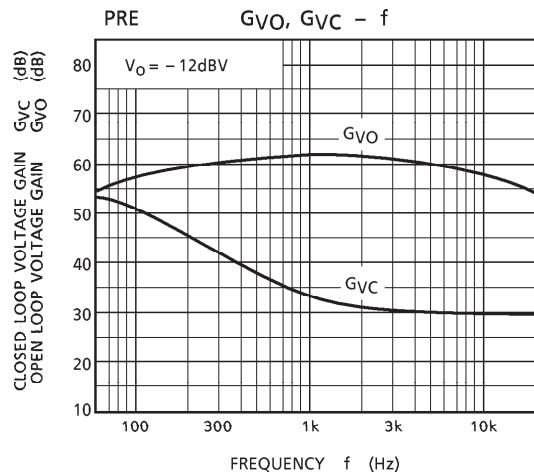
## TEST CIRCUIT

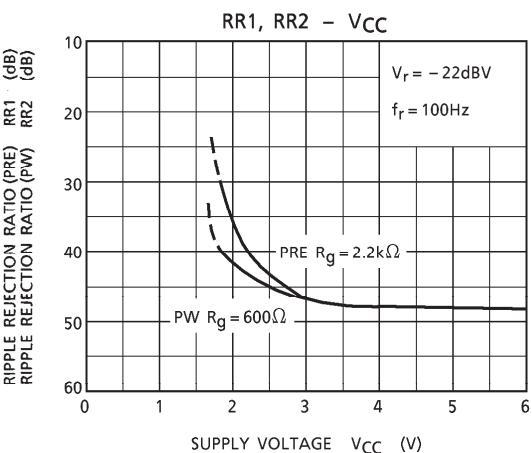
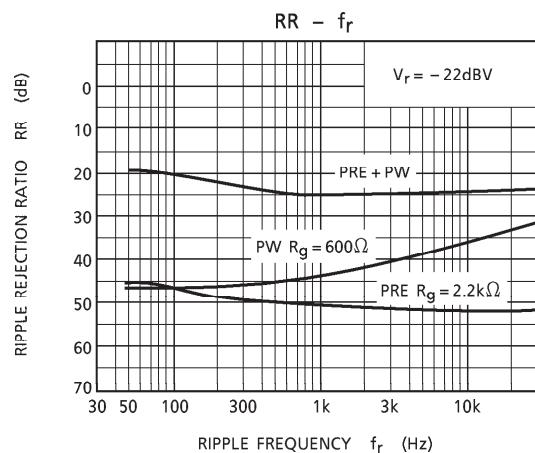
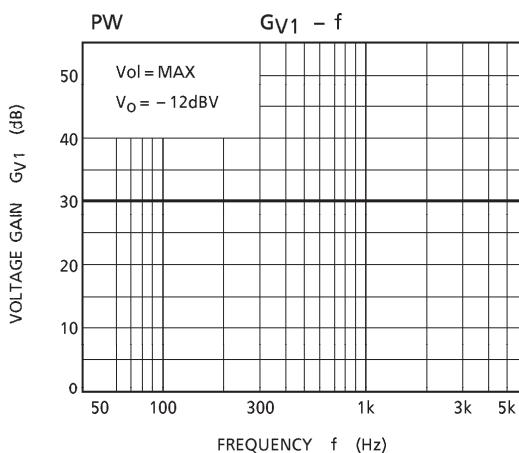
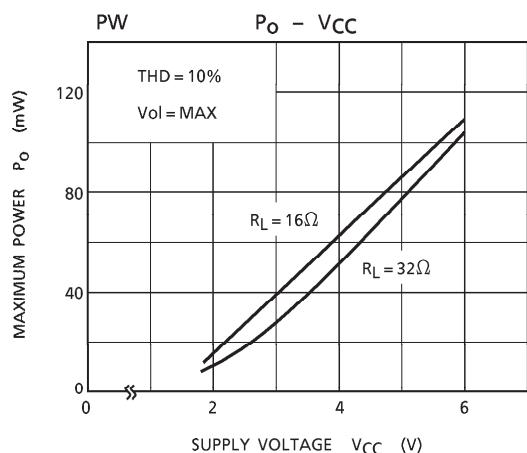
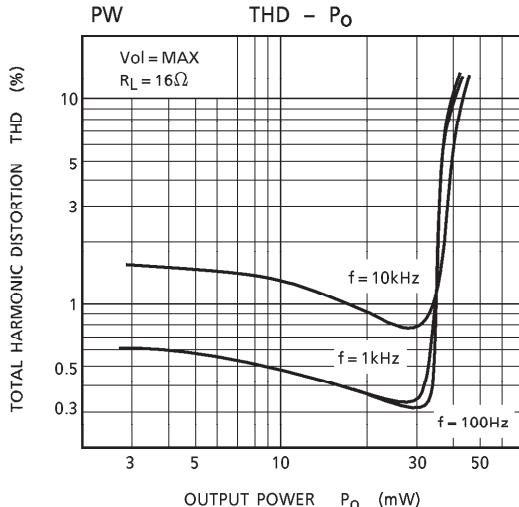
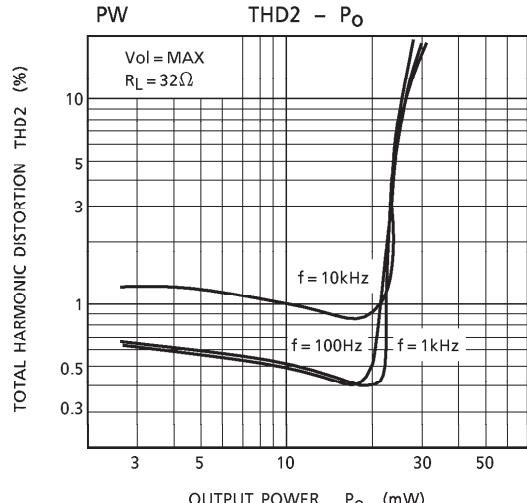


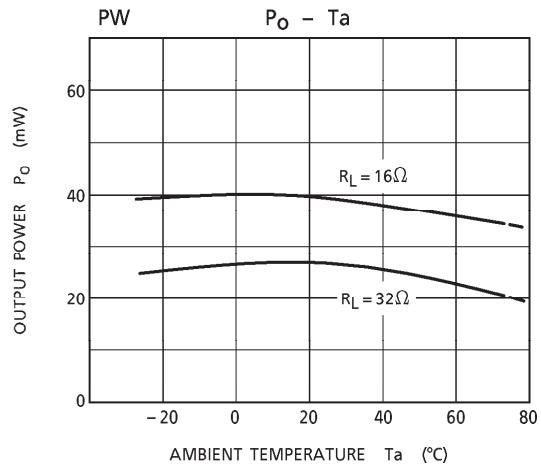
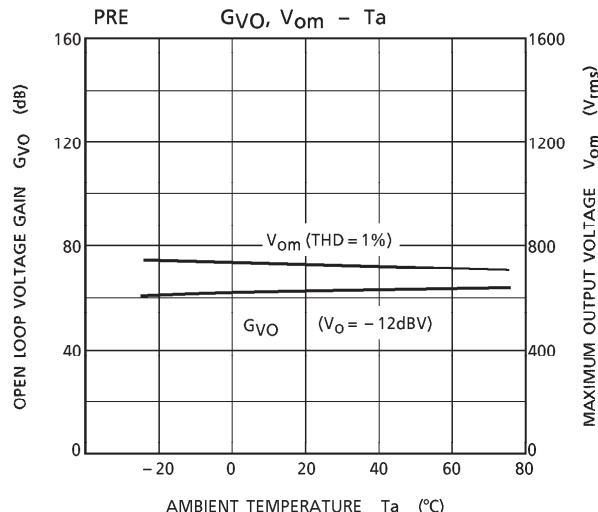
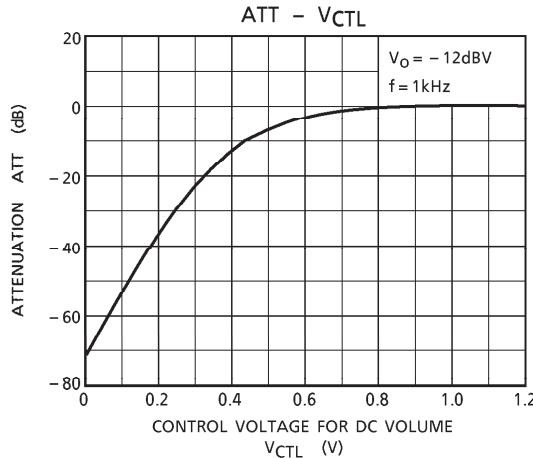
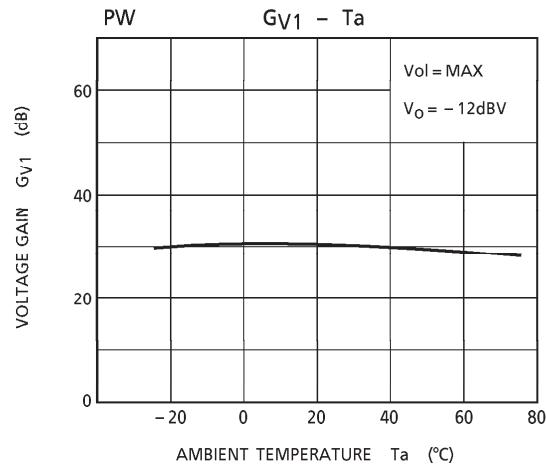
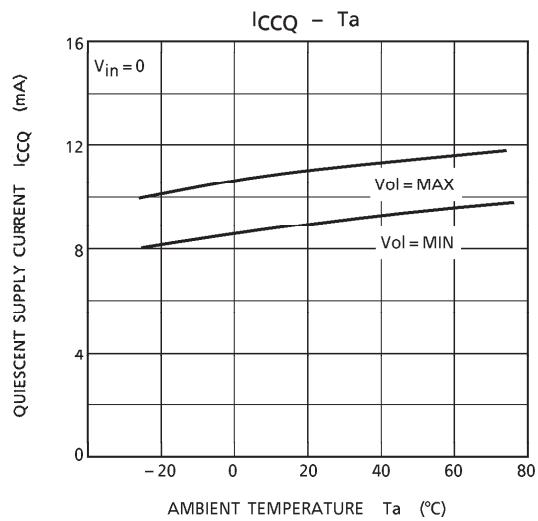
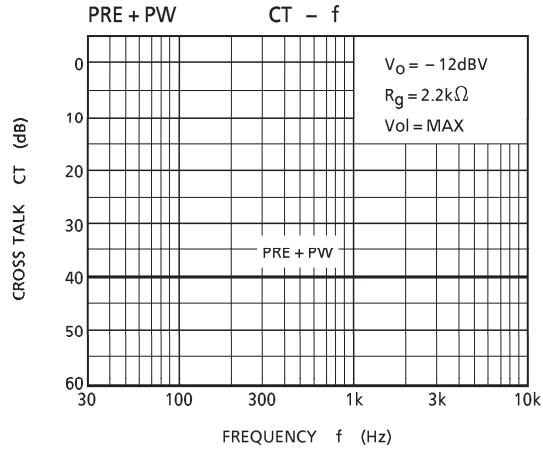
## SWITCH STATE FOR ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SW <sub>1</sub>	SW <sub>2</sub>	SW <sub>3</sub>	SW <sub>4</sub>	SW <sub>5</sub>	SW <sub>6</sub>	SW <sub>7</sub>	SW <sub>8</sub>
I <sub>CCQ1</sub>	x	x	a	a	b	c	○	a
I <sub>CCQ2</sub>	x	x	a	a	b	a	○	a
G <sub>VO</sub>	○	○	b	a	b	c	○	a
G <sub>VC</sub>	○	○	a	a	b	c	○	a
V <sub>om</sub>	○	○	a	a	b	c	○	a
THD1	○	○	a	a	b	c	○	a
V <sub>ni</sub>	x	x	a	a	b	c	○	a
RR1	x	x	a	a	b	c	x	a
P <sub>o1</sub>	x	x	a	a	a	a	○	a
P <sub>o2</sub>	x	x	a	a	a	a	○	b
G <sub>V1</sub>	x	x	a	a	a	a	○	a
CB	x	x	a	a	a	a	○	a
G <sub>V2</sub>	x	x	a	a	a	b	○	a
THD2	x	x	a	a	a	a	○	a
THD3	x	x	a	a	a	b	○	a
V <sub>no</sub>	x	x	a	a	b	a	○	a
ATT	x	x	a	a	a	a→c	○	a
RR2	x	x	a	a	b	c	x	a
CT	○ / x	x / ○	a	b	c	a	○	a

○ : short   x : open

**CHARACTERISTIC CURVES**Unless otherwise specified :  $V_{CC} = 3V$ ,  $f = 1\text{kHz}$ ,  $T_a = 25^\circ\text{C}$ Preamplifier :  $R_L = 10\text{k}\Omega$ ,  $\text{Vol} = \text{MIN}$ Power Amplifier :  $R_L = 32\Omega$ ,  $\text{Vol} = \text{MAX}$ 

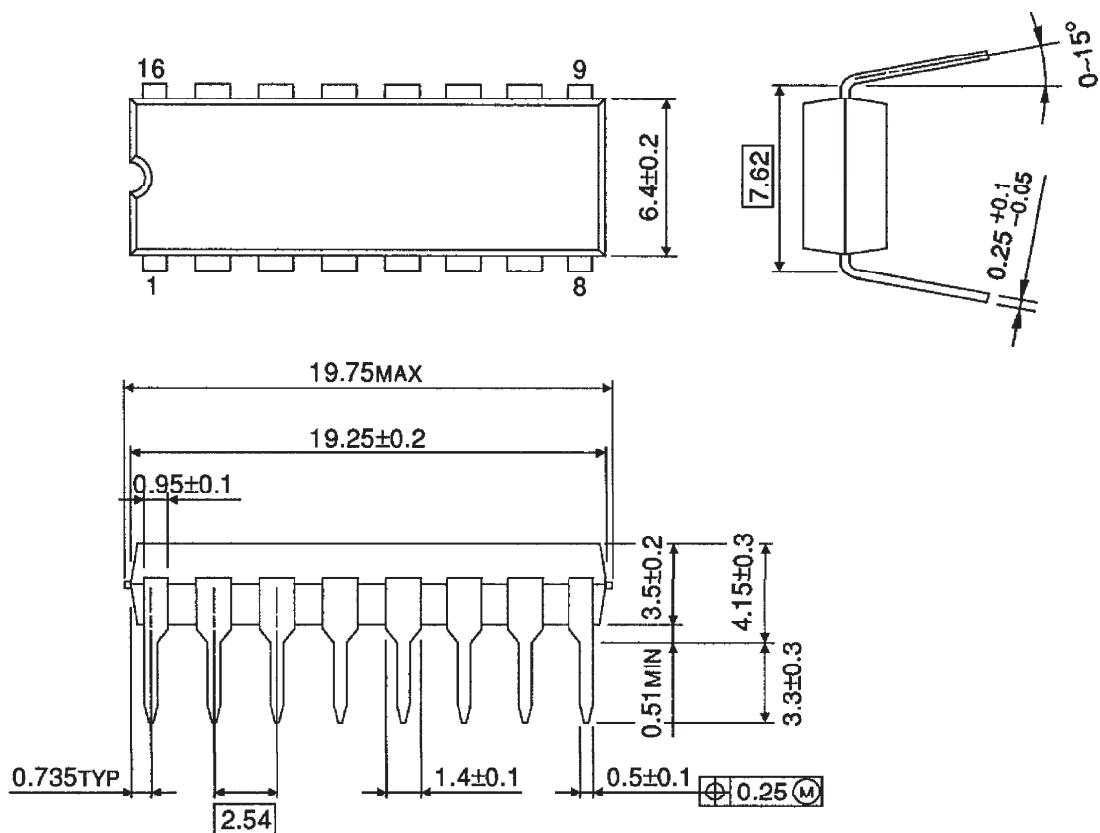




**OUTLINE DRAWING**

DIP16-P-300-2.54A

Unit : mm



Weight : 1.00g (Typ.)